



SGS-THOMSON MICROELECTRONICS

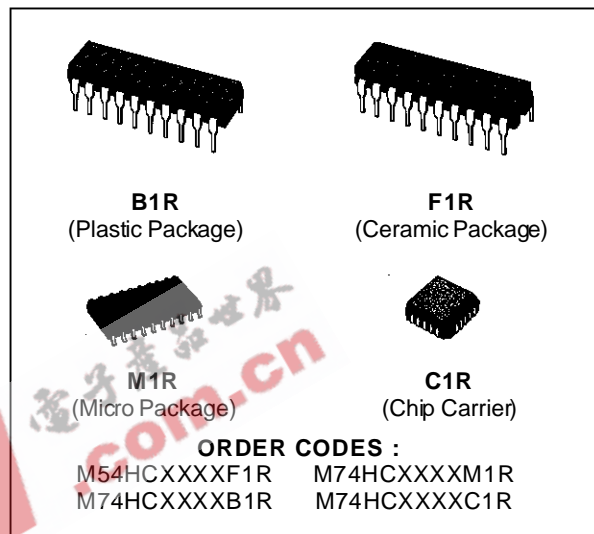
M54HC7240/7241/7244

M74HC7240/7241/7244

OCTAL BUS BUFFER WITH 3 STATE OUTPUTS

HC7240: INVERTED - HC7241/7244 NON INVERTED

- HIGH SPEED
 $t_{PD} = 15 \text{ ns (TYP.) at } V_{CC} = 5\text{V}$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu\text{A (MAX.) at } T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_H = 1.1 \text{ V (TYP.) at } V_{CC} = 5\text{V}$
- OUTPUT DRIVE CAPABILITY
 15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 6 \text{ mA (MIN)}$
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} \text{ (OPR)} = 2\text{V to } 6\text{V}$
- PIN AND FUNCTION COMPATIBLE
 WITH 54/74LS240/241/244



DESCRIPTION

The M54/74HC7240, HC7241 and HC7244 are high speed CMOS OCTAL BUS BUFFERS fabricated in silicon gate C²MOS technology.

They have the same high speed performance of LSTTL combined with true CMOS low power consumption.

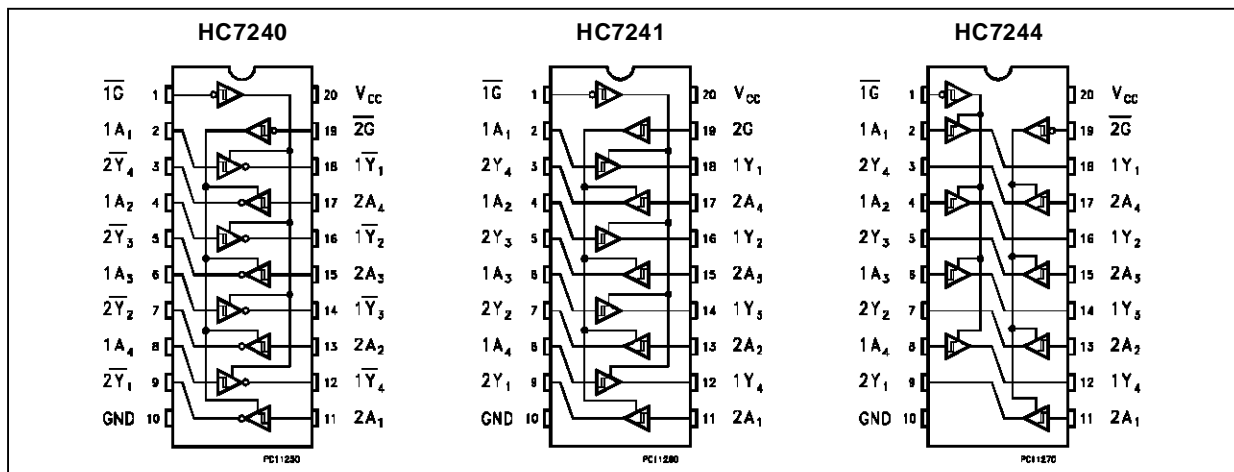
The designer has a choice of select combination of inverting and non-inverting outputs, symmetrical \bar{G} (active low output control) input, and complementary G and \bar{G} inputs. Each control input

governs four BUS BUFFERS.

The HC7240, HC7241 and HC7244 have the same pin configuration and function as the HC240, HC241 and HC244 and they have a hysteresis characteristics with each input so can be used as a line receiver, etc.

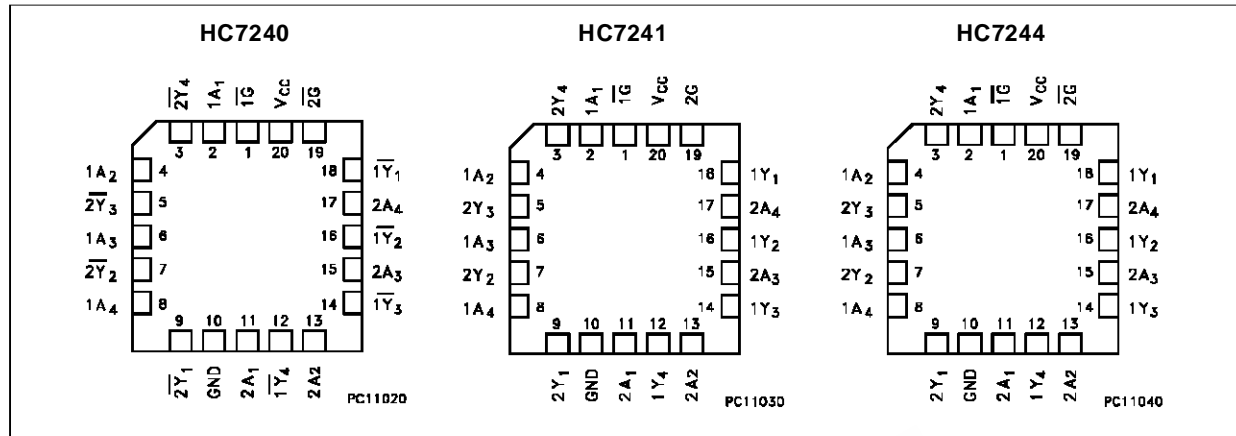
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION (top view)

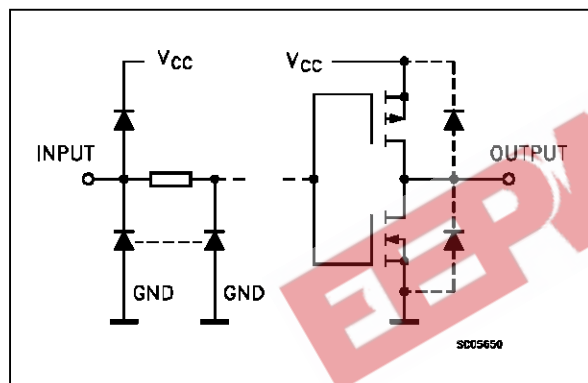


M54/M74HC7240/7241/7244

CHIP CARRIER



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION (HC7240)

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{1G}$	Output Enable Input
2, 4, 6, 8	1A1 to 1A4	Data Inputs
9, 7, 5, 3	2Y1 to 2Y4	Data Outputs
11, 13, 15, 17	2A1 to 2A4	Data Inputs
18, 16, 14, 12	$\overline{1Y1}$ to $\overline{1Y4}$	Data Outputs
19	$\overline{2G}$	Output Enabel Input
10	GND	Ground (0V)
20	V _{cc}	Positive Supply Voltage

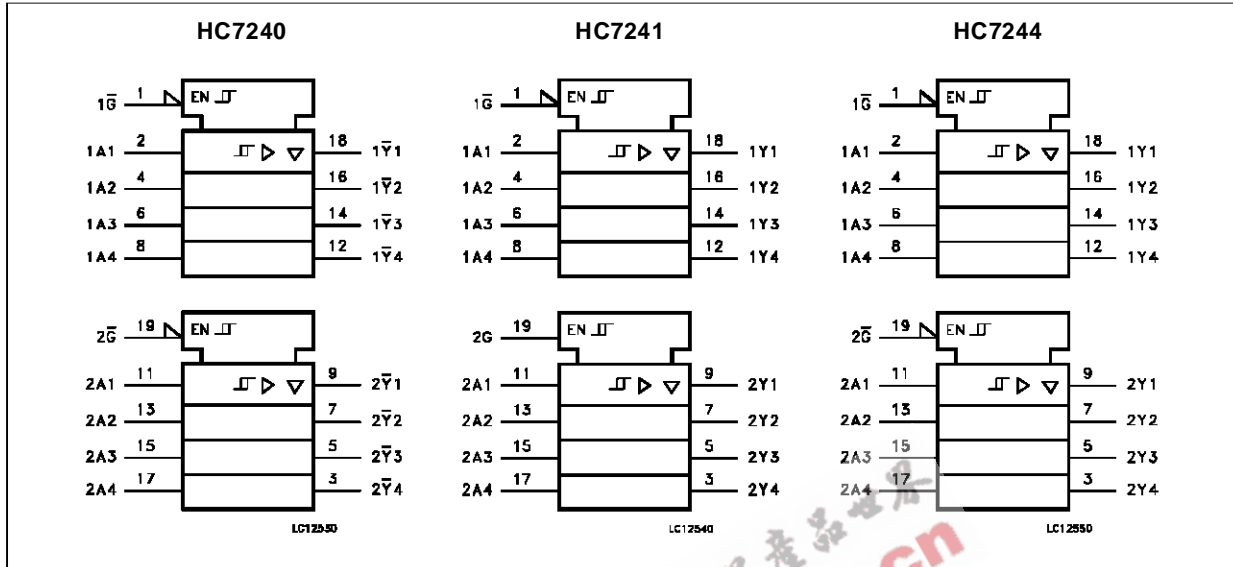
PIN DESCRIPTION (HC7241)

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{1G}$	Output Enable Input
2, 4, 6, 8	1A1 to 1A4	Data Inputs
9, 7, 5, 3	2Y1 to 2Y4	Data Outputs
11, 13, 15, 17	2A1 to 2A4	Data Inputs
18, 16, 14, 12	1Y1 to 1Y4	Data Outputs
19	2G	Output Enabel Input
10	GND	Ground (0V)
20	V _{cc}	Positive Supply Voltage

PIN DESCRIPTION (HC7244)

PIN No	SYMBOL	NAME AND FUNCTION
1	$\overline{1G}$	Output Enable Input
2, 4, 6, 8	1A1 to 1A4	Data Inputs
9, 7, 5, 3	2Y1 to 2Y4	Data Outputs
11, 13, 15, 17	2A1 to 2A4	Data Inputs
18, 16, 14, 12	1Y1 to 1Y4	Data Outputs
19	$\overline{2G}$	Output Enabel Input
10	GND	Ground (0V)
20	V _{cc}	Positive Supply Voltage

IEC LOGIC SYMBOLS

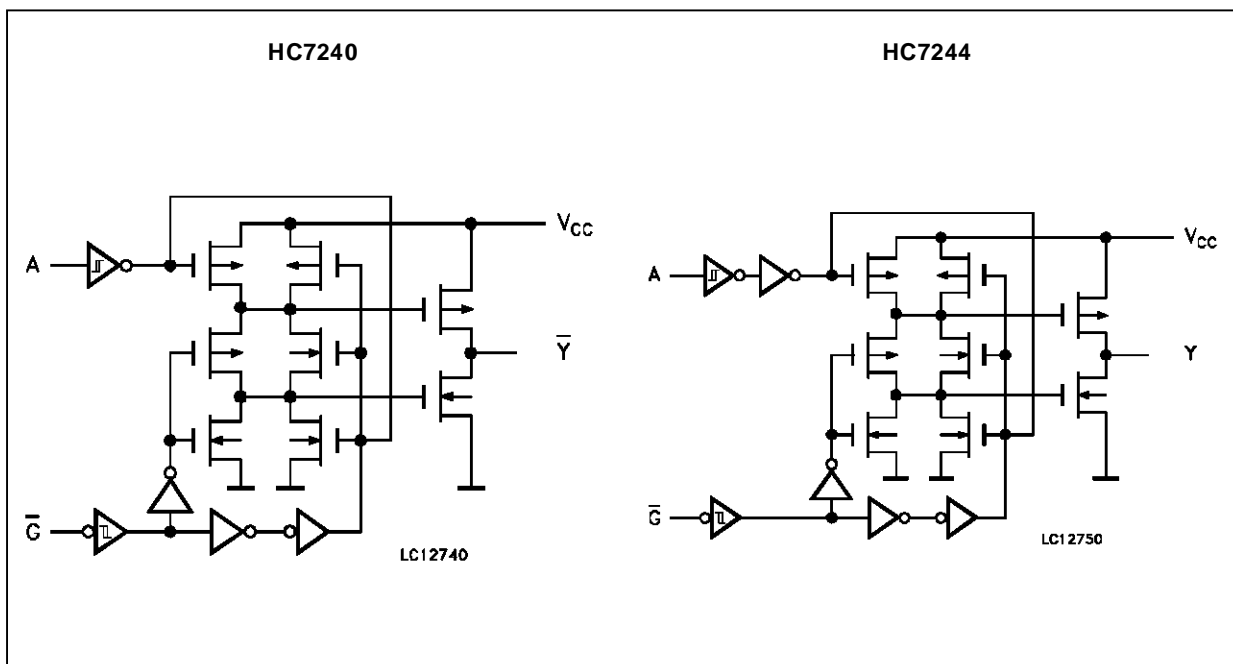


TRUTH TABLE

INPUT			OUTPUT		
\bar{G}	G (HC7241)	A_n	\bar{Y}_n (HC7240)	Y_n (HC7241)	Y_n (HC7244)
L	H	L	H	L	L
L	H	H	L	H	H
H	L	X	Z	Z	Z

X: "H" or "L"
Z: High impedance

CIRCUIT SCHEMATIC (1/8 PACKAGE)



M54/M74HC7240/7241/7244

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
V _I	DC Input Voltage	-0.5 to V _{CC} + 0.5	V
V _O	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
I _O	DC Output Source Sink Current Per Output Pin	± 35	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 70	mA
P _D	Power Dissipation	500 (*)	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	2 to 6	V
V _I	Input Voltage	0 to V _{CC}	V
V _O	Output Voltage	0 to V _{CC}	V
T _{op}	Operating Temperature: M54HC Series M74HC Series	-55 to +125 -40 to +85	°C °C

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value						Unit		
		V _{CC} (V)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC			
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.	
V _P	High Level Threshold Voltage	2.0		1.0	1.25	1.5	1.0	1.5	1.0	1.5	V	
		4.5		2.3	2.7	3.15	2.3	3.15	2.3	3.15		
		6.0		3.0	3.5	4.2	3.0	4.2	3.0	4.2		
V _N	Low Level Threshold Voltage	2.0		0.3	0.65	0.9	0.3	0.9	0.3	0.9	V	
		4.5		1.13	1.6	2.0	1.13	2.0	1.13	2.0		
		6.0		1.5	2.3	2.6	1.5	2.6	1.5	2.6		
V _H	Hysteresis Voltage	2.0		0.3	0.6	1.0	0.3	1.0	0.3	1.0	V	
		4.5		0.6	1.1	1.4	0.6	1.4	0.6	1.4		
		6.0		0.8	1.2	1.7	0.8	1.7	0.8	1.7		
V _{OH}	High Level Output Voltage	2.0	V _I = V _{IH} or V _{IL}	I _O = -20 μA	1.9	2.0		1.9		1.9	V	
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I _O = -6.0 mA	4.18	4.31		4.13		4.10		
		6.0		I _O = -7.8 mA	5.68	5.8		5.63		5.60		
V _{OL}	Low Level Output Voltage	2.0		I _O = 20 μA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I _O = 6.0 mA		0.17	0.26		0.33		0.40	
		6.0		I _O = 7.8 mA		0.18	0.26		0.33		0.40	
I _I	Input Leakage Current	6.0					±0.1		±1		±1	μA
I _{OZ}	3 State Output Off State Current	6.0					±0.5		±5		±10	μA
I _{CC}	Quiescent Supply Current	6.0					4		40		80	μA

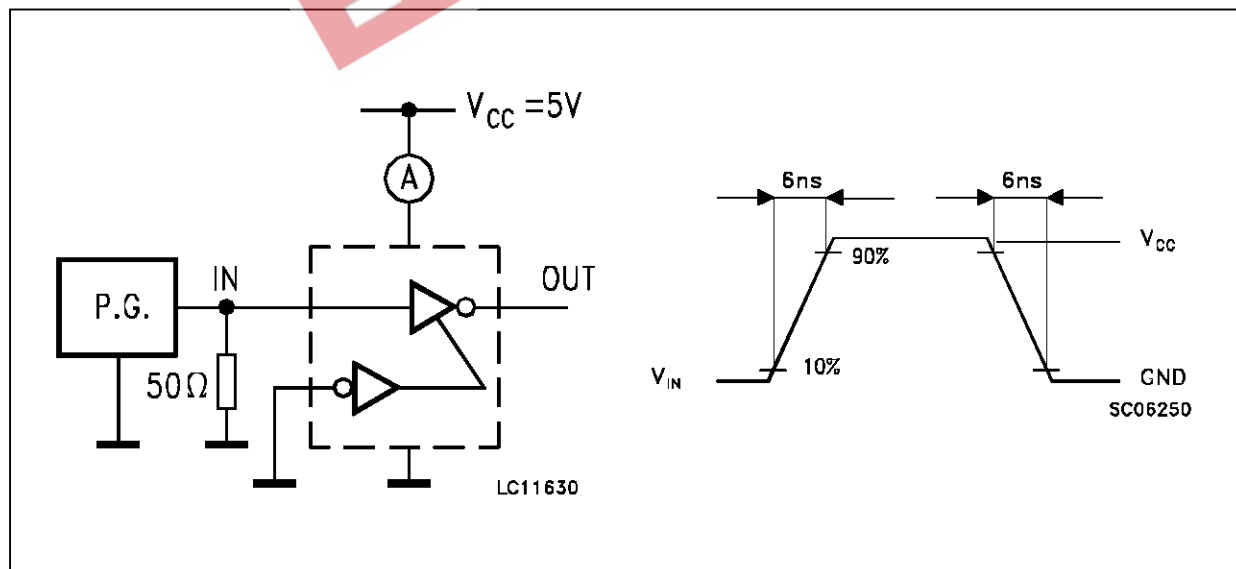
M54/M74HC7240/7241/7244

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

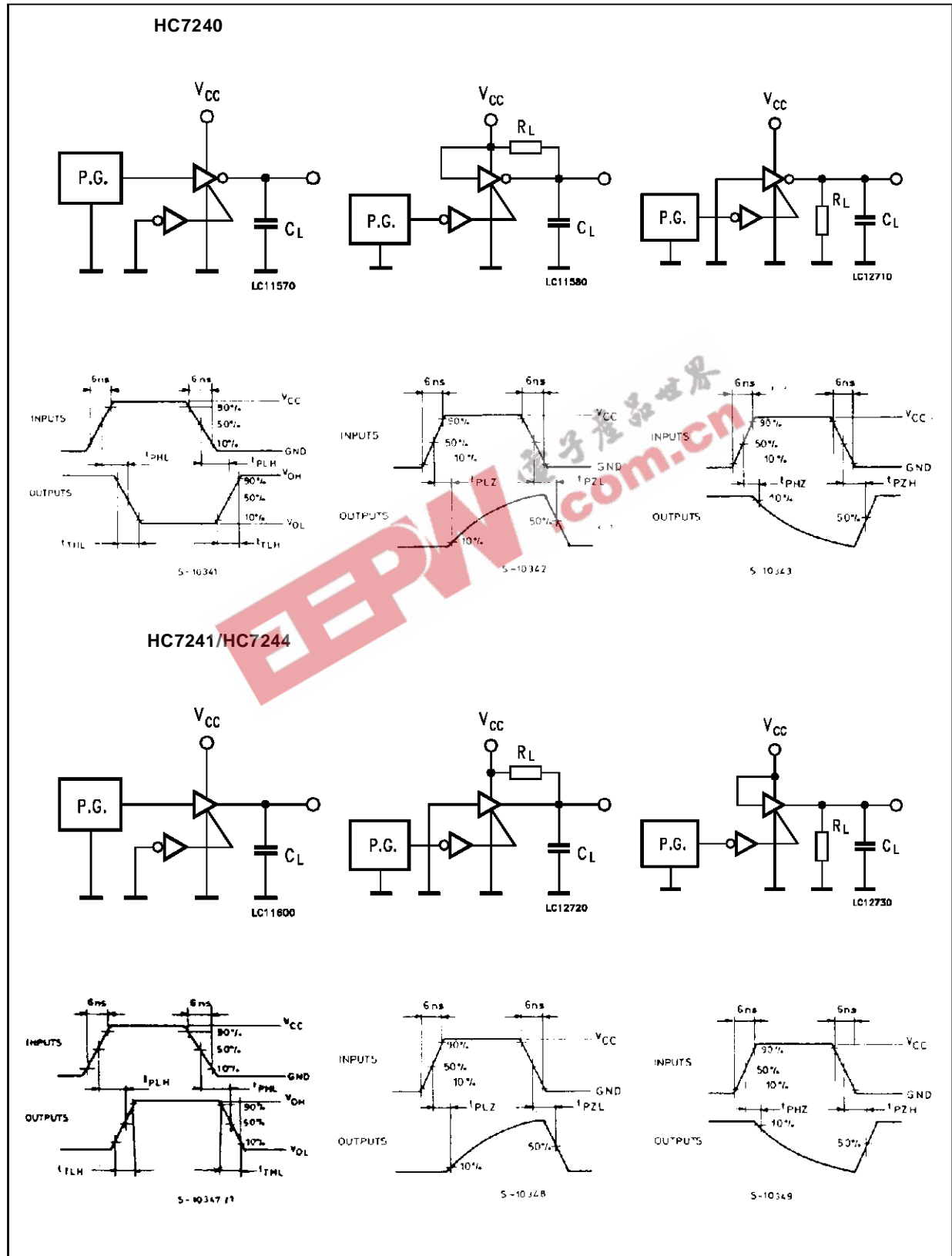
Symbol	Parameter	Test Conditions			Value						Unit	
		V_{CC} (V)	C_L (pF)		$T_A = 25 \text{ }^\circ\text{C}$ 54HC and 74HC			$-40 \text{ to } 85 \text{ }^\circ\text{C}$ 74HC		$-55 \text{ to } 125 \text{ }^\circ\text{C}$ 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t_{TLH} t_{THL}	Output Transition Time	2.0 4.5 6.0	50			25 7 6	60 12 10		75 19 13			ns
t_{PLH} t_{PHL}	Propagation Delay Time	2.0 4.5 6.0	50			50 15 13	125 25 21		155 31 26			ns
t_{PZL} t_{PZH}	Output Enable Time	2.0 4.5 6.0	50	$R_L = 1\text{K}\Omega$		68 21 16	150 30 26		190 38 32			ns
t_{PLZ} t_{PHZ}	Output Disable Time	2.0 4.5 6.0	50	$R_L = 1\text{K}\Omega$		48 21 19	150 30 26		190 38 32			ns
C_{IN}	Input Capacitance					5	10		10		10	pF
C_{OUT}	Output Capacitance					10						pF
$C_{PD} (*)$	Power Dissipation Capacitance			HC7240 HC7241/7244		33 34						pF

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per channel)

TEST CIRCUIT I_{CC} (Opr.)

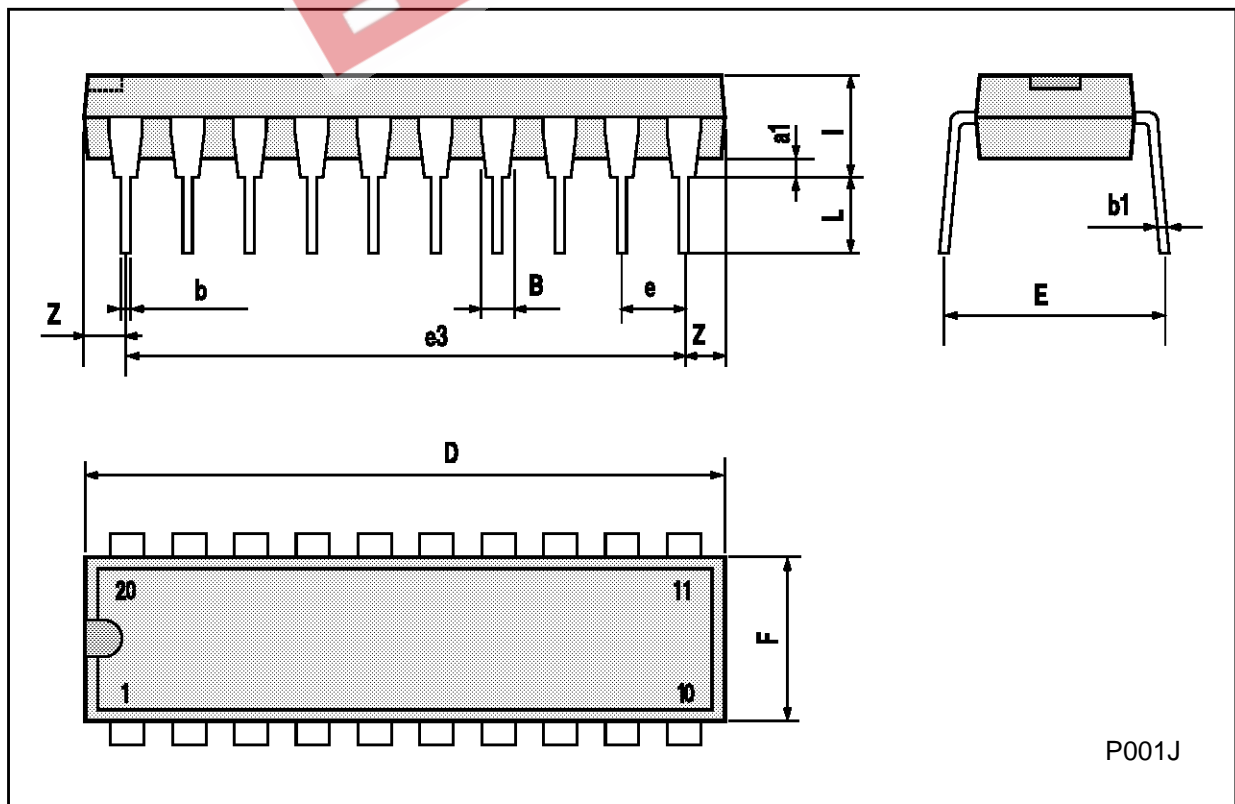


SWITCHING CHARACTERISTICS TEST CIRCUIT



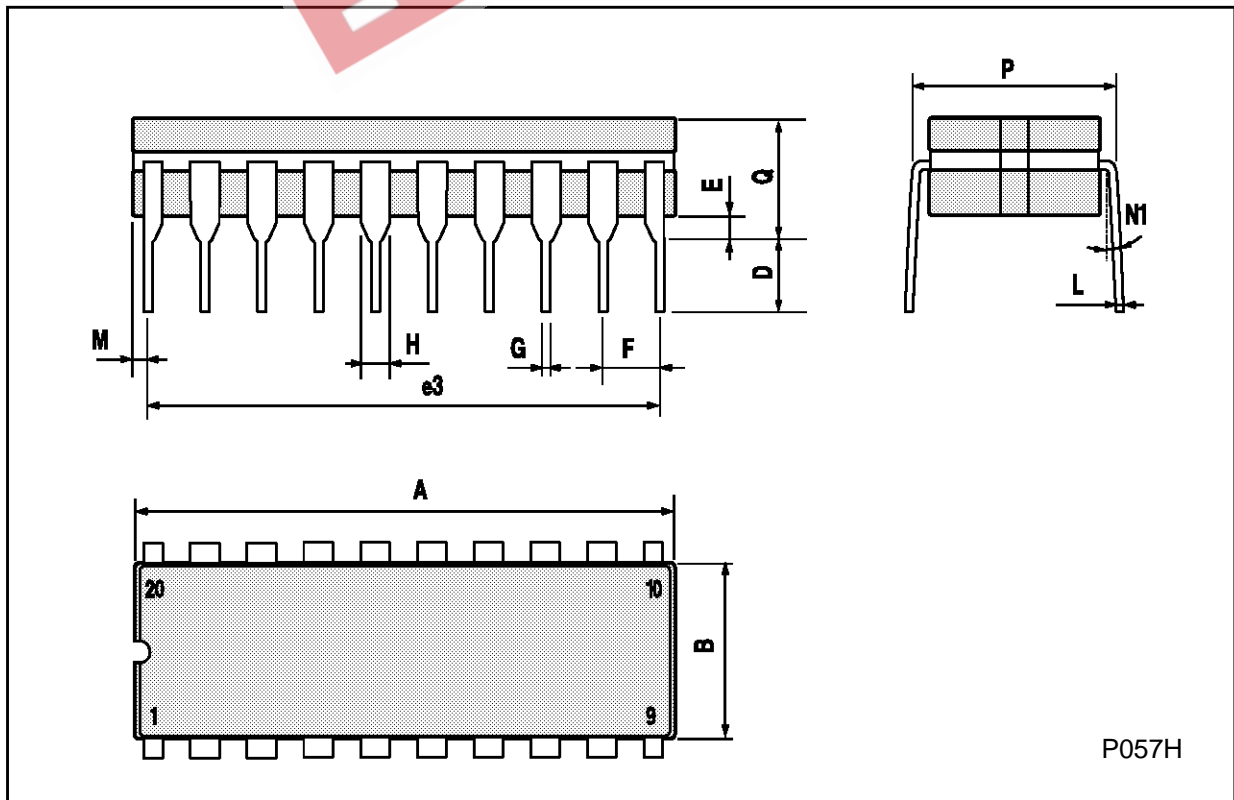
Plastic DIP20 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



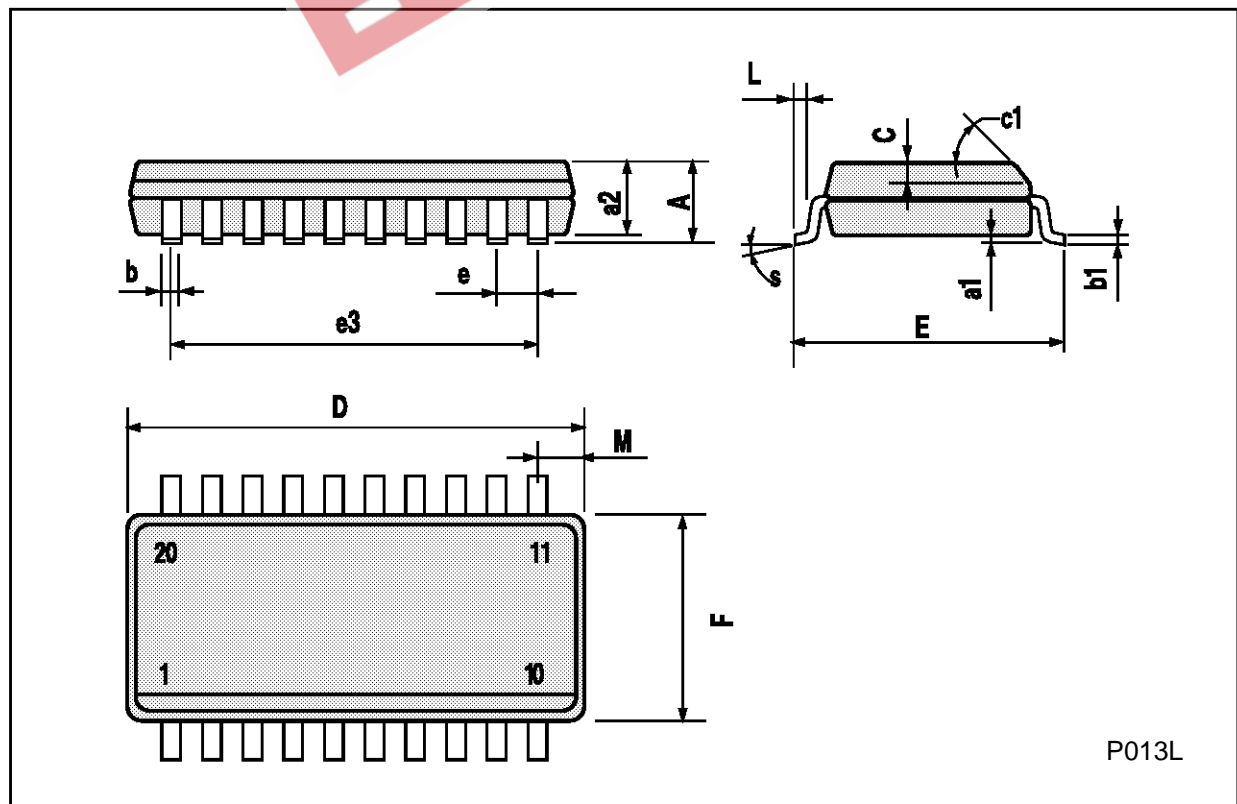
Ceramic DIP20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			25			0.984
B			7.8			0.307
D		3.3			0.130	
E	0.5		1.78	0.020		0.070
e3		22.86			0.900	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
I	1.27		1.52	0.050		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N1	4° (min.), 15° (max.)					
P	7.9		8.13	0.311		0.320
Q			5.71			0.225



SO20 MECHANICAL DATA

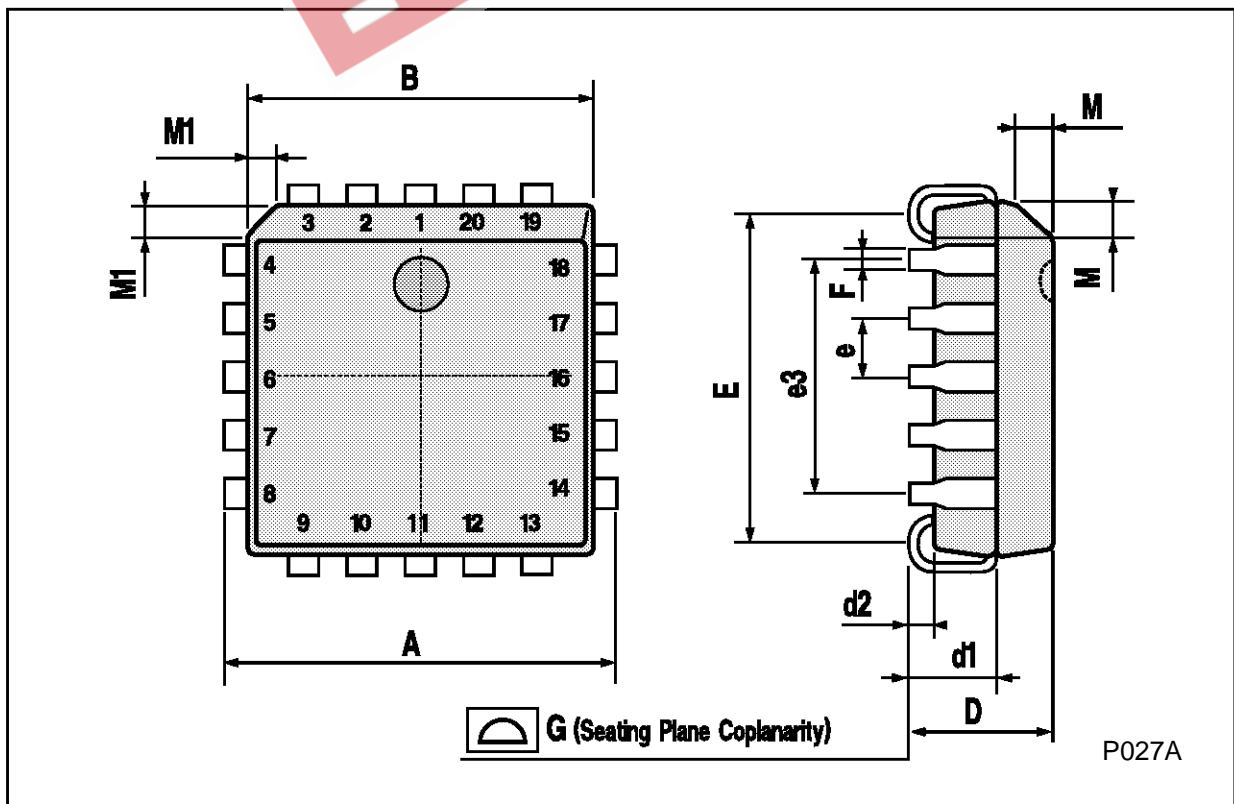
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45° (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S	8° (max.)					



P013L

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



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